



1200V SiC Schottky Diode

VDC	1200 V		
Q _c	318 nC***		
I _F	60 A***		
T _j ,max	175 °C		

Amp+[™] Features

- Unipolar rectifier with surge current
- Zero reverse recovery current
- · Fast, temperature-independent switching
- Avalanche tested to 400mJ per leg*
- All parts tested to greater than 1,400V

Amp+™ Benefits

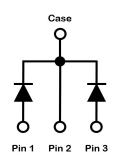
- Near zero switching loss
- Higher efficiency
- Smaller heat sink
- Easy to parallel

Amp+[™] Applications

- Solar Inverters
- · Switch mode power supplies, UPS
- Power factor correction
- · EV charging stations

Package





Part #	Package	Marking
GP3D060A120U	TO-247-3L	3D060A120



Maximum Ratings, at T_i=25 °C, unless otherwise specified

Characteristics Per Leg	Symbol	Conditions	Values	Unit	
Continuous forward current		T _C =25 °C, T _j =175 °C	74		
	I _{F**}	T _C =125 °C, T _j =175 °C	40	A	
		T _C =150 °C, T _j =175 °C	26		
Surge non-repetitive forward current		T _C =25 °C, t _p =8.3 ms	265	^	
sine halfwave	I _{FSM}	T _C =110 °C, t _p =8.3 ms	240	_ A	
Non-repetitive peak forward current	I _{F,max}	T _C =25 °C, t _p =10 μs	1500	А	
<i>i</i> ² <i>t</i> value	∫i²dt	T _C =25 °C, t _p =8.3 ms	291	.2	
		T _C =110 °C, t _p =8.3 ms	239	$ A^2$ s	
Repetitive peak reverse voltage	V_{RRM}	T _j =25 °C	1200	V	
Diode dv/dt ruggedness	dv/dt	Turn-on slew rate, repetitive	200	V/ns	
Power dissipation	P _{tot**}	T _C =25 °C	321	W	
Operating junction & storage temperature	$T_{j},T_{storage}$	Continuous	-55175	°C	
Soldering temperature	T _{solder}	Wave soldering leads	260	°C	
Mounting torque		M3 Screw	1	N-m	

Notes:

^{*} EAS of 400 mJ is based on starting Tj $_{=}$ 25°C, L = 1.0 mH, IAS = 28.28 A, V = 50 V.

^{**} Typical Rth_{JC} used

^{***} Per Device

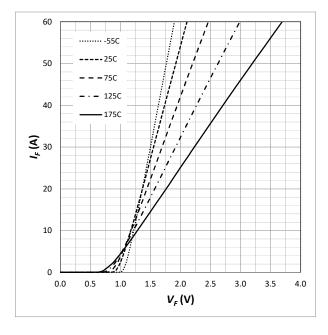
Electrical Characteristics, at T_j=25 °C, unless otherwise specified

Characteristics Per Leg	Symbol	Conditions	Values			Unit
	Syllibol		min.	typ.	max.	Onit
DC blocking voltage	V _{DC}	T _j =25 °C	1200	-	-	V
Breakdown voltage	V _{BR}	I _R =1.00mA, T _j =25 °C	1400	-	-	V
		I _F =30A, T _j =25 °C	-	1.54	1.70	V
Diode forward voltage	V_{F}	I _F =30A, T _j =125 °C	-	1.92	-	
		I _F =30A, T _j =175 °C	-	2.23	2.70	
Reverse current	I _R	V _R =1,200V, T _j =25 °C	-	2	60	μΑ
		V _R =1,400V, T _j =25 °C	-	9	-	
		V _R =1,200V, T _j =125 °C	-	15	-	
		V _R =1,200V, T _j =175 °C	-	69	900	
Total capacitive charge	Q _C	V _R =800V, T _j =25 °C	-	159	-	nC
Total capacitance	С	V _R =1V, f=1 MHz	-	1762	-	pF
		V _R =400V, f=1 MHz	-	150	-	
		V _R =800V, f=1 MHz	-	108	-	

Thermal Characteristics

Characteristics Per Leg	Symbol	Symbol Conditions	Values			Unit
Cilaracteristics Fer Leg			min.	typ.	max.	Ollit
Thermal resistance, junction-case	R _{thJC}	-	-	0.47	0.62	°C/W

Typical Performance Per Leg





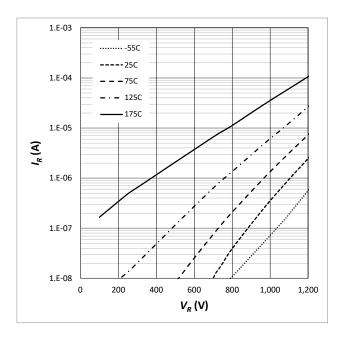
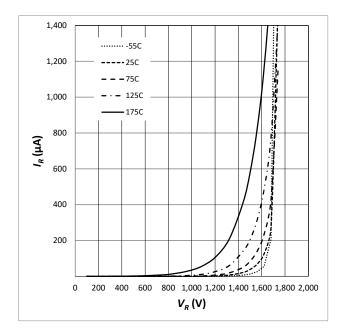


Fig. 2 Reverse Characteristics (parameterized on T_i)



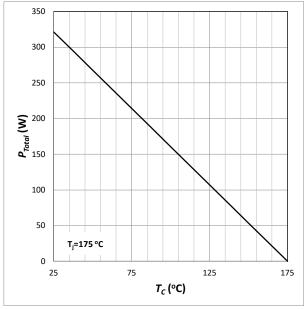
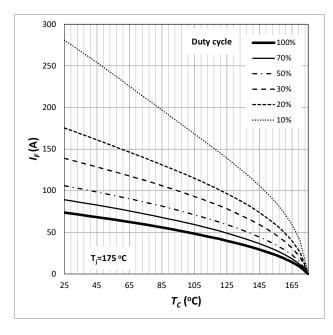


Fig. 3 Reverse Characteristics (parameterized on Tj)

Fig. 4 Power Derating





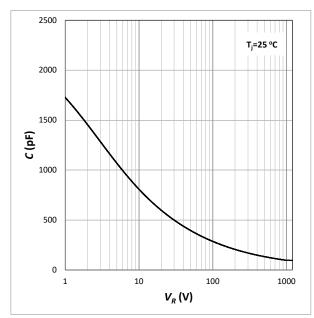
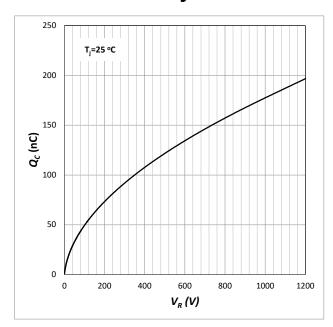


Fig. 6 Capacitance



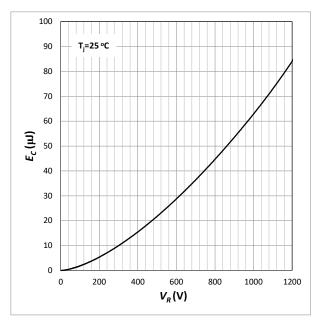


Fig. 7 Capacitive Charge

Fig. 8 Typical Capacitance Stored Energy

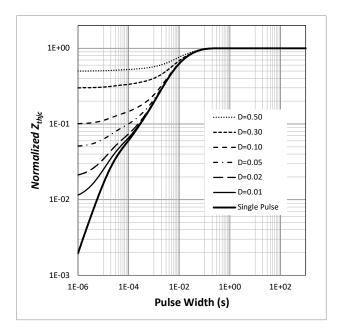
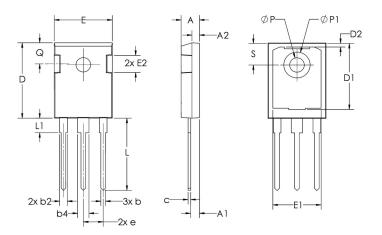


Fig. 9 Transient Thermal Impedance

Package Dimensions TO-247-3L



Curro	Millimeters		Inc	nes	
Sym	Min	Max	Min	Max	
Α	4.70	5.31	0.185	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b2	1.65	2.39	0.065	0.094	
b4	2.59	3.43	0.102	0.135	
С	0.38	0.89	0.015	0.035	
D	20.80	21.46	0.819	0.845	
D1	13.08	17.65	0.515	0.695	
D2	0.51	1.35	0.020	0.053	
E	15.49	16.26	0.610	0.640	
E1	13.46	14.16	0.530	0.557	
E2	3.43	5.49	0.135	0.216	
е	5.44 BSC		0.214 BSC		
L	19.81	20.32	0.780	0.800	
L1	4.10	4.50	0.161	0.177	
ØP	3.56	3.66	0.140	0.144	
ØP1	7.06	7.39	0.278	0.291	
Q	5.39	6.20	0.212	0.244	
S	6.04	6.30	0.238	0.248	

Notes

RoHS Compliance

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS2), as implemented March, 2013. RoHS Declarations for this product can be obtained from the Product Documentation sections of www.SemiQ.com.

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